

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA75072P, TA75072S, TA75072F

DUAL OPERATIONAL AMPLIFIER

The TA75072P, TA75072S and TA75072F are J-FET input low-noise operational amplifiers with low input bias and offset current, fast slew rate and wide bandwidth.

The TA75072P is pin compatible with the TA75458P and 1458. The TA75072S is single-in-line package.

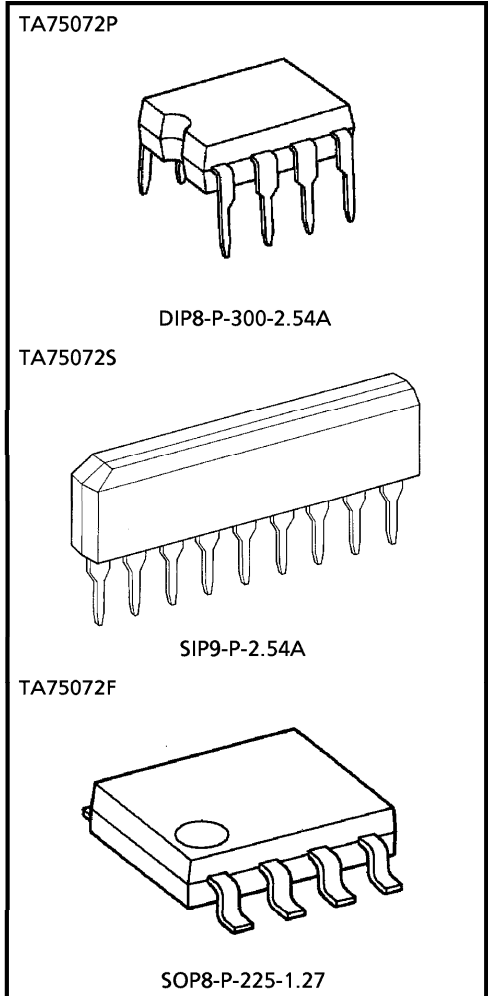
It is possible to exchange the position of 9 pin for 1 pin because of pin connection being symmetric.

The TA75072F is mini-flat package.

The TA75072P series are excellent choice for active filters, integrators, buffers and sample-and-hold circuits.

FEATURES

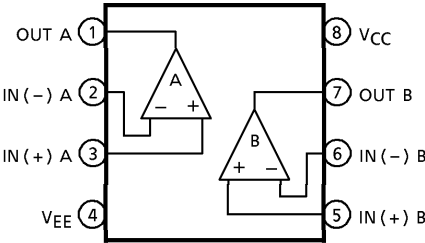
- Low Input Bias Current : 200pA MAX.
- Low Input Offset Current : 50pA MAX.
- High Slew Rate : $13V / \mu s$
- Low Noise : $18nV / \sqrt{Hz}$
- Wide Bandwidth : 3MHz
- Wide Supply Voltage Range : $\pm 4 \sim \pm 18V$
- Internal Frequency Compensation
- Output Short Circuit Protection



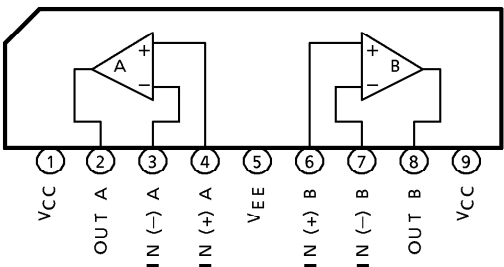
Weight
DIP8-P-300-2.54A : 0.5g (Typ.)
SIP9-P-2.54A : 0.9g (Typ.)
SOP8-P-225-1.27 : 0.1g (Typ.)

PIN CONNECTION (TOP VIEW)

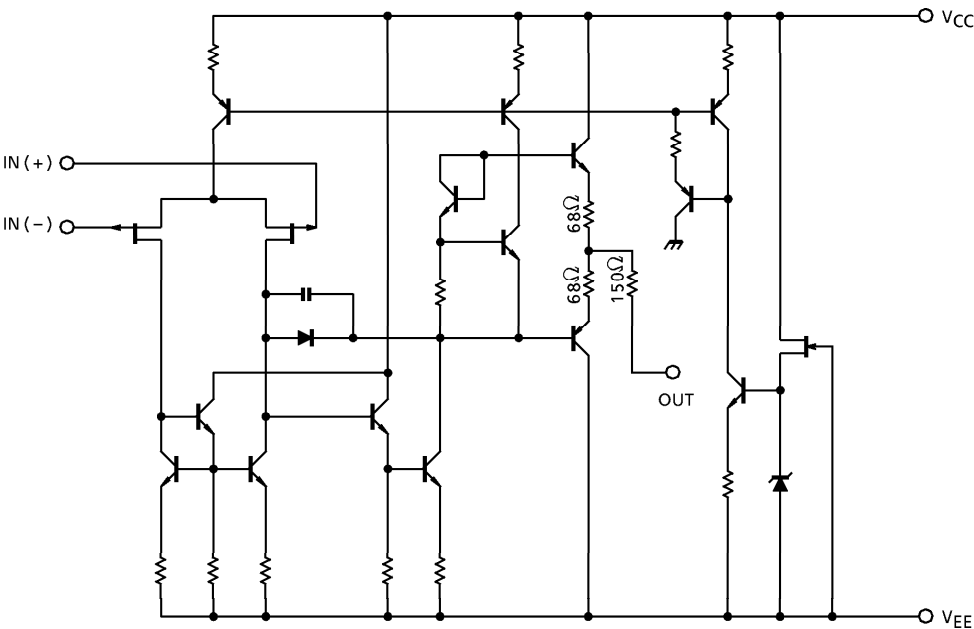
TA75072P, TA75072F



TA75072S



EQUIVALENT CIRCUIT



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage		V _{CC}	+ 18	V
		V _{EE}	- 18	
Differential Input Voltage		DV _{IN}	± 30	V
Input Voltage		V _{IN}	± 15	V
Power Dissipation	TA75072P	P _D	500	mW
	TA75072S			
	TA75072F		240	
Operating Temperature		T _{opr}	- 40~85	°C
Storage Temperature		T _{stg}	- 55~125	°C

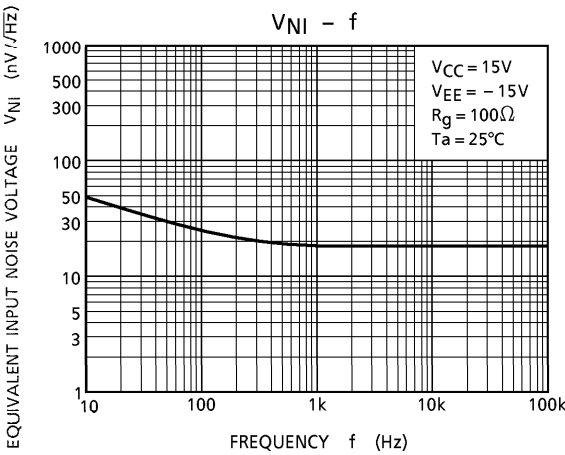
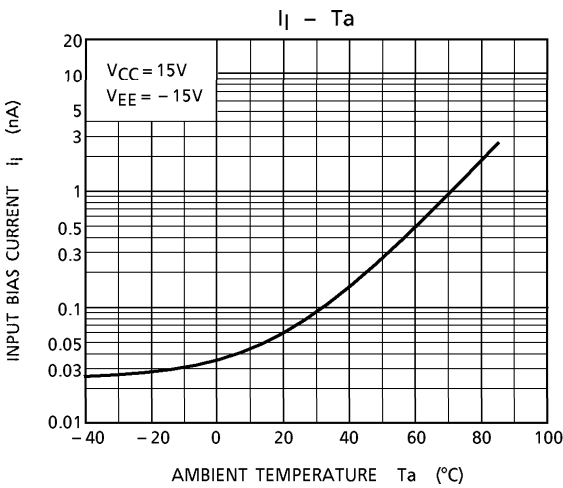
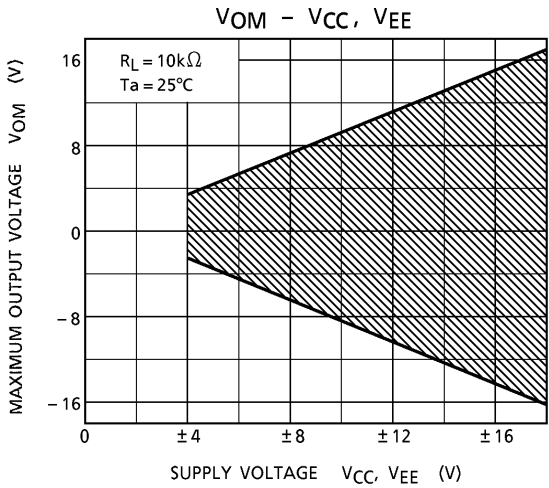
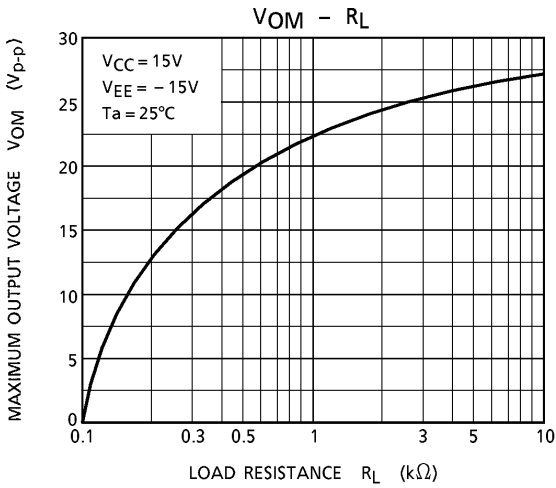
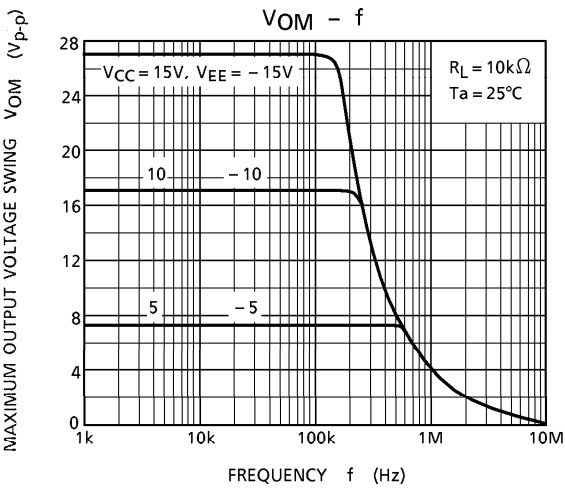
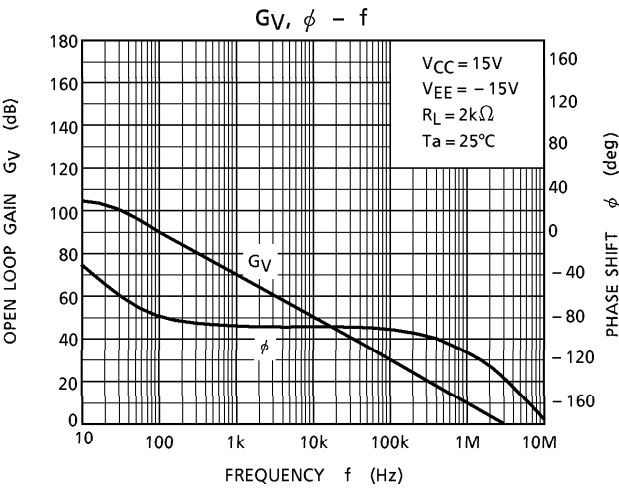
ELECTRICAL CHARACTERISTICS ($V_{CC} = 15V$, $V_{EE} = -15V$, $T_a = 25^\circ C$)

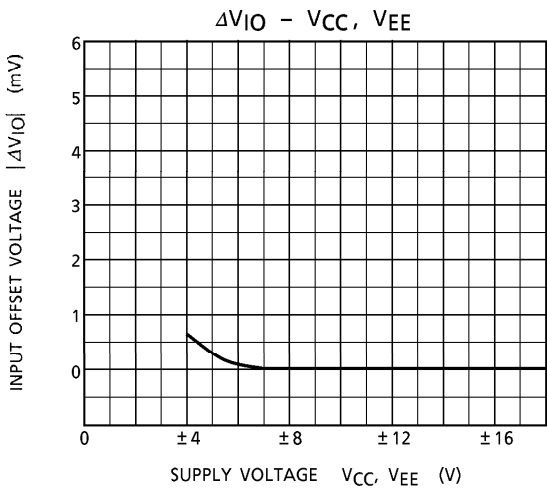
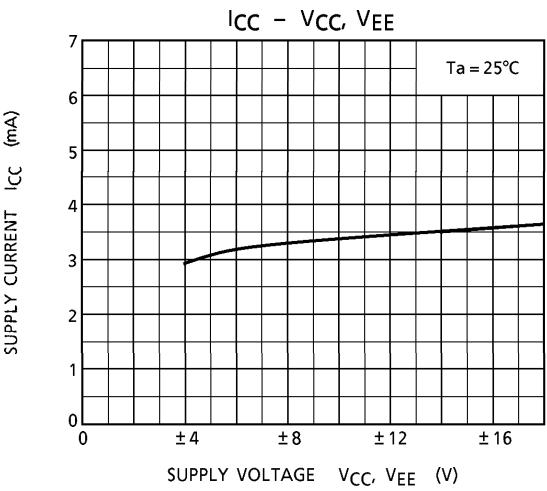
CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	—	$R_g \leq 10k\Omega$	—	3	10	mV
TC Of Input Offset Voltage	TCV_{IO}	—	—	—	10	—	$\mu V / ^\circ C$
Input Offset Current	I_{IO}	—	—	—	5	50	pA
Input Bias Current	I_I	—	—	—	30	200	pA
Common Mode Input Voltage	CMV_{IN}	—	—	± 11	± 12	—	V
Maximum Output Voltage	V_{OM}	—	$R_L = 10k\Omega$	24	—	—	V_{p-p}
	V_{OMR}	—	$R_L = 2k\Omega$	20	24	—	
Voltage Gain (Open Loop)	G_V	—	$V_{OUT} = \pm 10V$, $R_L = 2k\Omega$	25	200	—	V / mV
Unity Gain Cross Frequency	f_T	—	Open Loop, $R_L = 10k\Omega$	—	3	—	MHz
Input Resistance	R_{IN}	—	—	—	10^{12}	—	Ω
Common Mode Input Signal Rejection Ratio	CMRR	—	$R_g \leq 10k\Omega$	70	76	—	dB
Supply Voltage Rejection Ratio	SVRR	—	$R_g \leq 10k\Omega$	70	76	—	dB
Supply Current	I_{CC} , I_{EE}	—	Non load	—	2.8	5.0	mA
Cross Talk		—	—	—	-120	—	dB

OPERATING CHARACTERISTICS ($V_{CC} = 15V$, $V_{EE} = -15V$, $T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	—	$V_{IN} = 10V_{p-p}$, $R_L = 2k\Omega$ $C_L = 100pF$	—	13	—	$V / \mu s$
Equivalent Input Noise Voltage	V_{NI}	—	$R_S = 100\Omega$	$f = 1kHz$	18	—	$nV / \sqrt{Hz}$
				$f = 10Hz \sim 10kHz$	4	—	μV_{rms}
Equivalent Input Noise Current	I_{NI}	—	$R_S = 100\Omega$, $f = 1kHz$	—	0.01	—	$pA / \sqrt{Hz}$
Total Harmonic Distortion	THD	—	$V_{OUT} = 10V_{rms}$, $R_S \leq 1k\Omega$ $R_L \geq 2k\Omega$, $f = 1kHz$	—	0.01	—	%

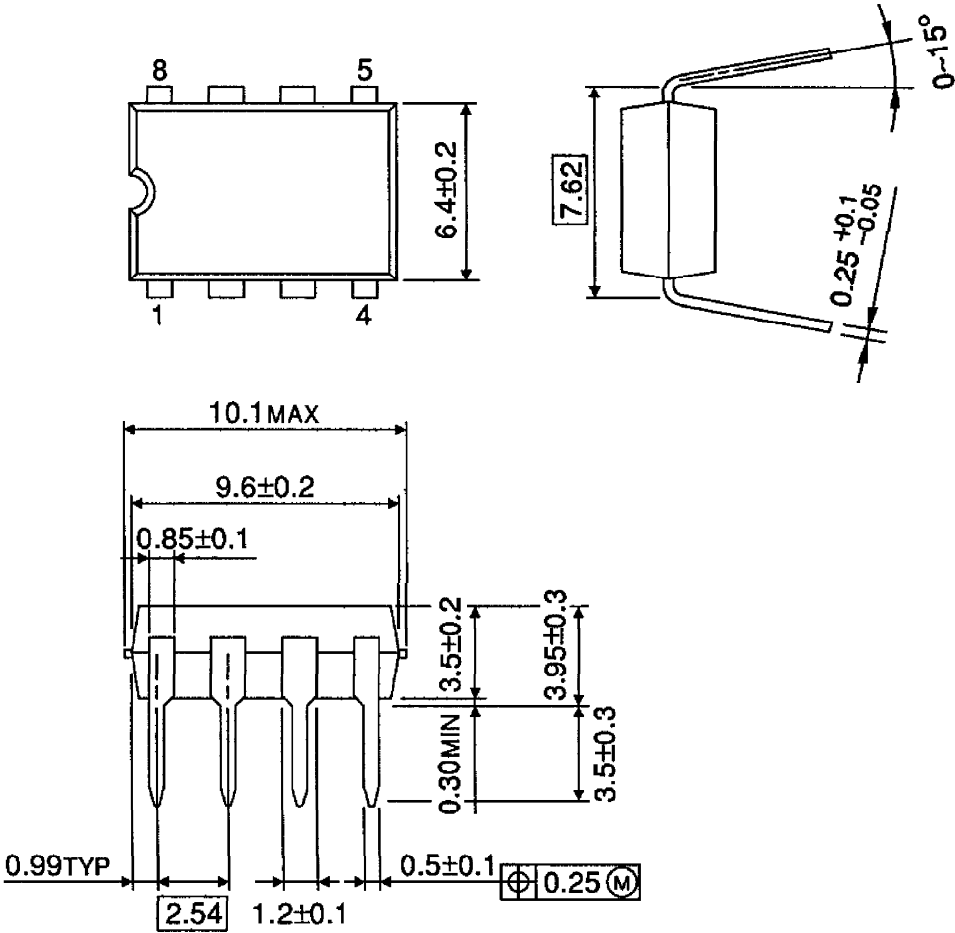
CHARACTERISTICS





PACKAGE DIMENSIONS
DIP8-P-300-2.54A

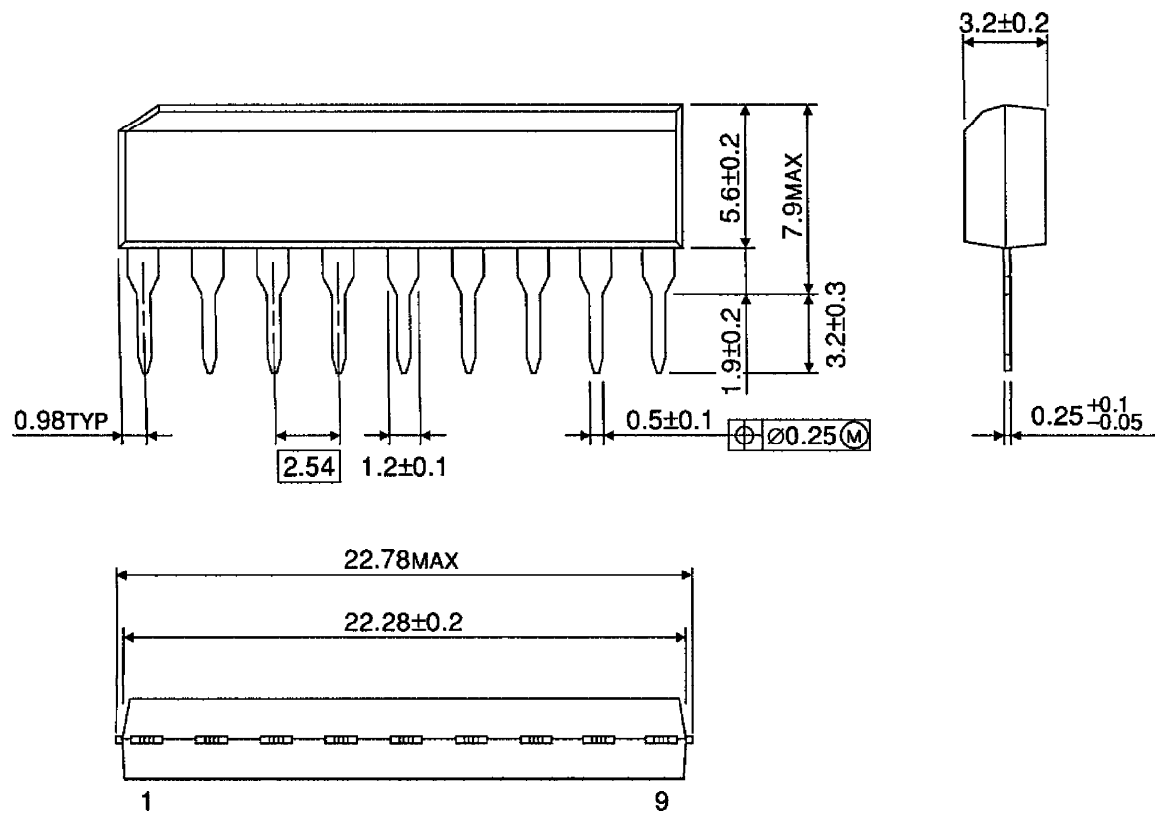
Unit : mm



Weight : 0.5g (Typ.)

PACKAGE DIMENSIONS
SIP9-P-2.54A

Unit : mm



Weight : 0.9g (Typ.)

SOP8-P-225-1.27

0.595 TYP

1.27

0.25 (M)

0.4 ± 0.1

4

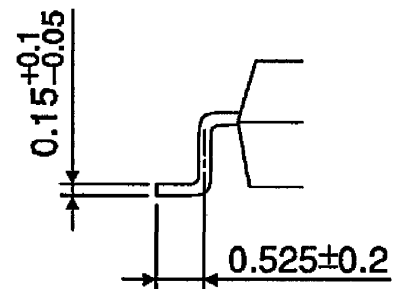
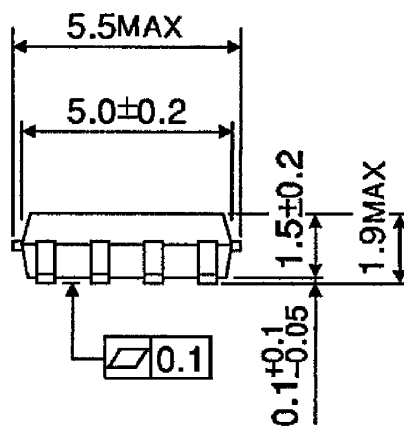
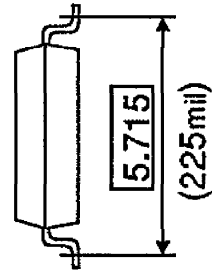
1

4.4 ± 0.2

6.3 ± 0.3

5

8



2001-06-19

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